

View Online at <https://aerobasegroup.com/nsn/5961-00-515-3296>

**Inclosure Material:**

Metal

**Overall Length:**

Between 0.240 inches and 0.290 inches

**Overall Height:**

Between 0.030 inches and 0.080 inches

**Overall Width:**

Between 0.120 inches and 0.154 inches

**Component Name And Quantity:**

2 transistor

**Mounting Method:**

Press fit

**Features Provided:**

Burn in and hermetically sealed case

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

40.0 collector to base voltage, dc all transistor and 40.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor

**Current Rating Per Characteristic:**

1.00 amperes source cutoff current all transistor

**Power Rating Per Characteristic:**

350.0 milliwatts small-signal input power, common-collector absolute all transistor

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius junction

**Special Features:**

All transistor junction pattern arrangement: pnp

**Terminal Type And Quantity:**

6 ribbon

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fig:**

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